U.S. DEPARTMENT OF COMMERCE  
PATENT AND TRADEMARK OFFICE**INFORMATION DISCLOSURE  
STATEMENT**Docket Number  
10020/26301Application Number  
**10/810,853**Filing Date  
March 29, 2004Examiner  
Not Yet AssignedArt Unit  
1762Invention Title  
**METHOD AND APPARATUS FOR  
DEPOSITING MATERIALS WITH HIGH  
RESOLUTION**Inventor(s)  
FORREST et al.Address to:  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450I hereby certify that this correspondence is being deposited with the United States  
Postal Service with sufficient postage as first class mail in an envelope addressed to:  
Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450 onDate: 7/13/04Signature: Thomas F. Meagher  
Thomas F. Meagher (Reg. No. 29,831)

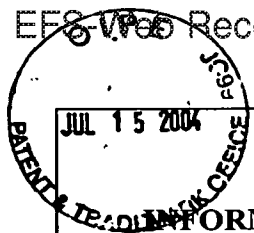
1. In accordance with the duty of disclosure under 37 C.F.R. § 1.56 and in conformance with the procedures of 37 C.F.R. §§ 1.97 and 1.98 and M.P.E.P. § 609, attorneys for Applicants hereby bring the following references to the attention of the Examiner. The references are listed on the attached modified PTO Form No. 1449. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the references be made of record therein and appear among the "References Cited" on any patent to issue therefrom.
2. Since the U.S. Patent and Trademark Office has waived the requirement under 37 C.F.R. § 1.98 (a)(2)(i) to submit a copy of each cited U.S. Patent and each U.S. patent application publication for all U.S. national patent applications filed after June 30, 2003, copies of the U.S. patents and U.S. patent application publications listed on the modified PTO Form No. 1449 are not enclosed.
3. It is believed that no fees are due in connection with this Information Disclosure Statement. However, should any fees be due, the Commissioner is authorized to charge Deposit Account No. 11-0600 for such fees. A duplicate copy of this communication is enclosed for charging purposes.

Dated: 7/13/04By: Thomas F. Meagher

Thomas F. Meagher (Reg. No. 29,831)

KENYON & KENYON  
One Broadway  
New York, NY 10004  
(212) 425-7200 (telephone)  
(212) 425-5288 (facsimile)

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| <b>INFORMATION DISCLOSURE<br/>STATEMENT BY APPLICANT<br/>PTO-1449</b> | DOCKET NO.<br>10020/26301            | SERIAL NO.<br><b>10/810,853</b> |
|   | APPLICANT<br>FORREST et al.          |                                 |
|   | FILING DATE<br><b>March 29, 2004</b> | GROUP<br>Not Yet Assigned       |

**U. S. PATENT DOCUMENTS**

| EXAMINER<br>INITIAL | PATENT<br>NUMBER | PATENT<br>DATE | NAME           | CLASS | SUBCLASS | FILING<br>DATE* |
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**FOREIGN PATENT DOCUMENTS**

| EXAMINER<br>INITIAL | DOCUMENT<br>NUMBER | DATE | COUNTRY | CLASS | SUBCLASS | TRANSLATION |    |
|---------------------|--------------------|------|---------|-------|----------|-------------|----|
|                     |                    |      |         |       |          | YES         | NO |
|                     |                    |      |         |       |          |             |    |
|                     |                    |      |         |       |          |             |    |

**OTHER DOCUMENTS**

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|---|----------------------|-----------------|------------|
| EXAMINER  | /Yewebdar T Tadesse/ | DATE CONSIDERED | 07/01/2008 |
| EXAMINER: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. |                      |                 |            |